



Contribution ID: 744

Type: **Talk (preferred)**

Nanoscale-Engineered InGaN/GaN Quantum Wells via Machine Learning Design

Monday 12 December 2022 15:15 (15 minutes)

We present the machine learning design of nanoscale-engineered InGaN-based QW with ten sublayers for enhanced performance based on a heuristic algorithm. Such a design approach can achieve significant improvements in the material gain characteristics and current density of QW.

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Session Classification: Conference on Optoelectronic and Microelectronic Materials and Devices

Track Classification: COMMAD: COMMAD: Advanced computational and machine learning methods in photonics, nanoelectronics, and devices